





60V NPN DARLINGTON TRANSISTOR IN SOT89

Features

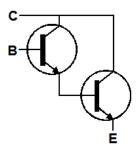
- BV_{CEO} > 60V
- Darlington Transistor h_{FE} > 10k @ 100mA for High Gain
- I_C = 500mA High Continuous Collector Current
- Complementary Darlington PNP Type: FCX705
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

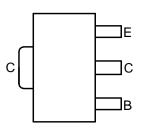
- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (23)
- Weight 0.052 grams (Approximate)







Device Symbol



Top View Pin-Out

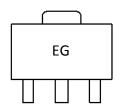
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BCV49TA	AEC-Q101	EG	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/

Marking Information



EG = Product Type Marking Code



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	$V_{\sf CEO}$	60	V
Emitter-Base Voltage	V_{EBO}	10	V
Continuous Collector Current	lc	500	mA
Peak Pulse Current	Ісм	800	mA

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 5)	D	1.1	W	
Power Dissipation	(Note 6)	P_D	1.5		
Thermal Decistores Innetion to Ambient	(Note 5)	<u> </u>	113	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	83	- C/VV	
Thermal Resistance, Junction to Leads (Note 7)		$R_{ heta JL}$	9.9	°C/W	
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

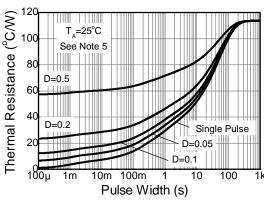
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

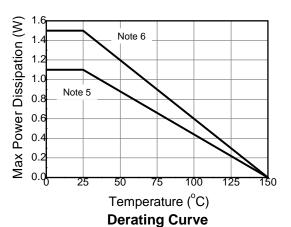
- 5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
- 7. Thermal resistance from junction to solder-point (on the exposed collector pad).
- 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

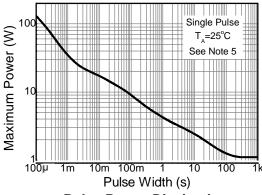


Thermal Characteristics and Derating Information









Pulse Power Dissipation



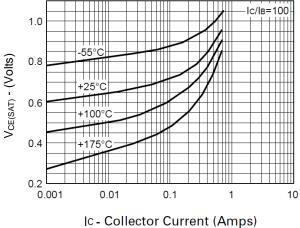
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	80	_	_	V	$I_C = 100\mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	60	_	_	V	I _{CEO} = 10mA
Emitter-Base Breakdown Voltage	BV _{EBO}	10	_	_	V	$I_{EBO} = 10\mu A$
Collector Cut-Off Current	Ісво	_	<1 —	100 10	nΑ μΑ	V _{CB} = 60V V _{CB} = 60V, T _A = +150°C
Emitter-Base Cut-Off Current	I _{EBO}	_	<1	100	nA	$V_{EB} = 4V$
ON CHARACTERISTICS (Note 9)						·
Static Forward Current Transfer Ratio	h _{FE}	2,000 4,000 10,000 2,000		_	_	$\begin{split} &I_{C} = 100 \mu A, V_{CE} = 1 V \\ &I_{C} = 10 m A, V_{CE} = 5 V \\ &I_{C} = 100 m A, V_{CE} = 5 V \\ &I_{C} = 500 m A, V_{CE} = 5 V \end{split}$
Collector-Emitter Saturation Voltage	V _{CE(SAT)}	_	_	1.0	V	$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$
Base-Emitter Saturation Voltage	V _{BE(SAT)}	_	_	1.5	V	$I_C = 100 \text{mA}, I_B = 0.1 \text{mA}$
SMALL SIGNAL CHARACTERISTICS (Note 9)						
Transition Frequency	f _T	_	170	_	MHz	$I_C = 50$ mA, $V_{CE} = 5$ V, $f = 20$ MHz
Output Capacitance	C _{OBO}	_	3.5	_	pF	$V_{CB} = 10V$, $f = 1MHz$

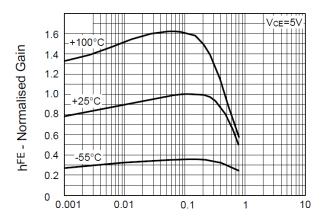
Note 9: Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.



Typical Electrical Characteristics

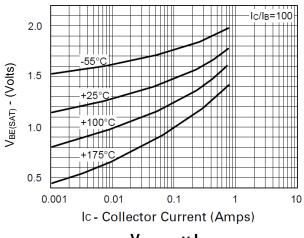


$V_{\text{CE(SAT)}} v I_{\text{C}}$

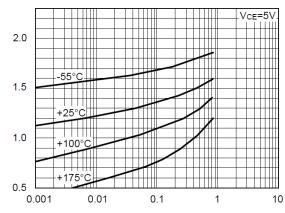


Ic - Collector Current (Amps)

hFE v IC



 $V_{\text{BE(SAT)}} v I_{\text{C}}$



I_C - Collector Current (Amps) $V_{BE(ON)} v I_C$

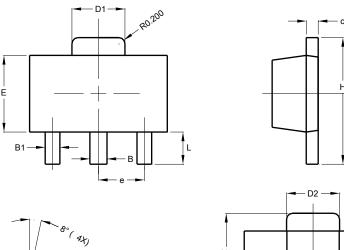
VBE - (Volts)



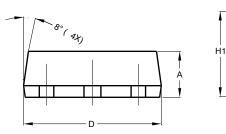
Package Outline Dimensions

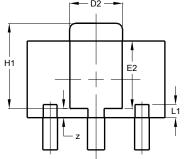
Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



SOT89					
Dim	Min	Max	Тур		
Α	1.40	1.60	1.50		
В	0.50	0.62	0.56		
B1	0.42	0.54	0.48		
С	0.35	0.43	0.38		
D	4.40	4.60	4.50		
D1	1.62	1.83	1.733		
D2	1.61	1.81	1.71		
Е	2.40	2.60	2.50		
E2	2.05	2.35	2.20		
е	-	-	1.50		
Н	3.95	4.25	4.10		
H1	2.63	2.93	2.78		
L	0.90	1.20	1.05		
L1	0.327	0.527	0.427		
Z	0.20	0.40	0.30		
All	All Dimensions in mm				

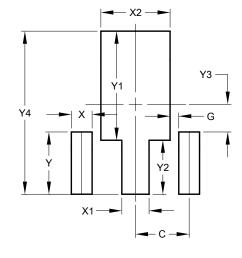




Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT89



Dimensions	Value
פווטופווסוווט	(in mm)
С	1.500
G	0.244
X	0.580
X1	0.760
X2	1.933
Υ	1.730
Y1	3.030
Y2	1.500
Y3	0.770
Y4	4.530



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